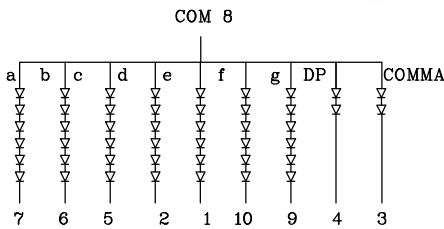


Features

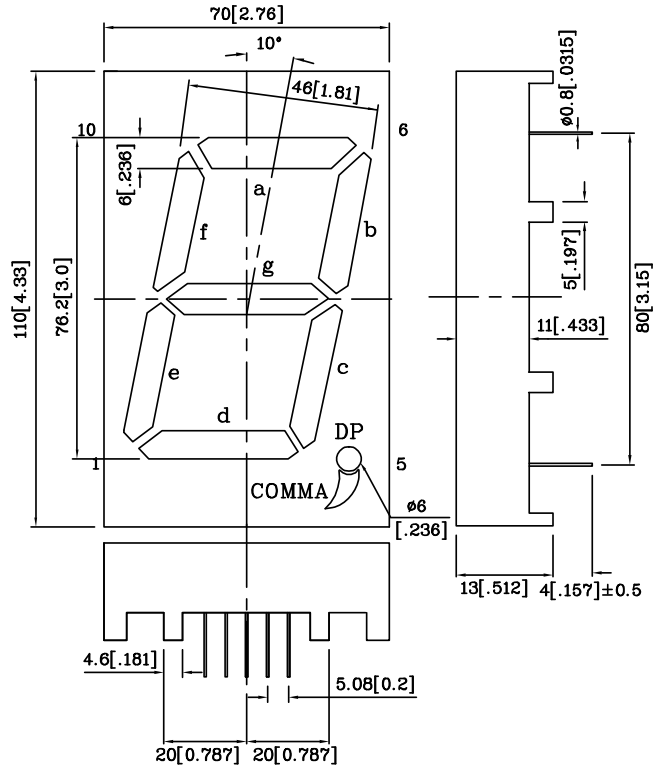
- 3.0 INCH DIGIT HEIGHT.
- LOW CURRENT OPERATION.
- EXCELLENT CHARACTER APPEARANCE.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- I.C. COMPATIBLE.
- CATEGORIZED FOR LUMINOUS INTENSITY.
- MECHANICALLY RUGGED.
- STANDARD : GRAY FACE, WHITE SEGMENT.
- RoHS COMPLIANT.



Notes:

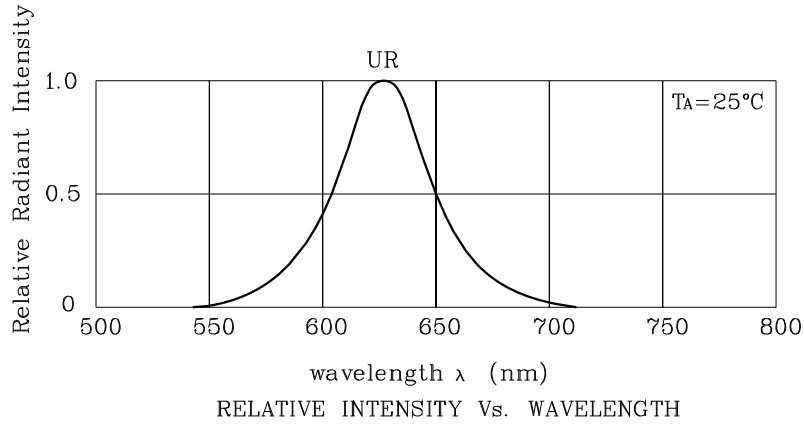
1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
3. Specifications are subject to change without notice.

Absolute maximum ratings (TA=25°C)		UR (GaAsP/GaP)	Unit
Reverse Voltage Per Segment or (Dp and Comma)	V _R	30 (10)	V
Forward Current Per Segment or (Dp and Comma)	I _F	30 (30)	mA
Forward Current (Peak) Per Segment or (Dp and Comma) 1/10 Duty Cycle 0.1ms Pulse Width	i _{FS}	160 (160)	mA
Power Dissipation Per Segment or (Dp and Comma)	P _T	450 (150)	mW
Operating Temperature	T _A	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +85	
Lead Solder Temperature [2mm Below Package Base]	260°C For 3~5 Seconds		

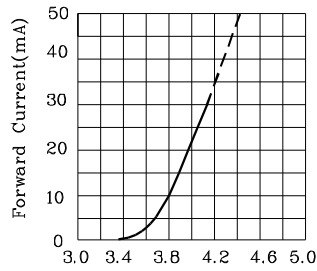


Operating Characteristics (TA=25°C)		UR (GaAsP/GaP)	Unit
Forward Voltage (Typ.) Per Segment or (Dp and Comma) (I _F =10mA)	V _F	11.4 (3.8)	V
Forward Voltage (Max.) Per Segment or (Dp and Comma) (I _F =10mA)	V _F	15.0 (5.0)	V
Reverse Current Per Segment or (Dp and Comma) (V _R =30(10)V)	I _R	10 (10)	uA
Wavelength Of Peak Emission (Typ.) (I _F =10mA)	λ _P	627	nm
Wavelength Of Dominant Emission (Typ.) (I _F =10mA)	λ _D	625	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I _F =10mA)	Δλ	45	nm
Capacitance (Typ.) (V _F =0V, f=1MHz)	C	15	pF

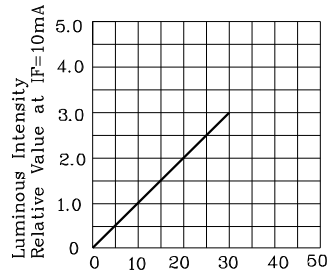
Part Number	Emitting Color	Emitting Material	Luminous Intensity (I _F =10mA) ucd		Wavelength nm λ _P	Description
			min.	typ.		
DUR76A	Red	GaAsP/GaP	3000	13990	627	Common Anode, Rt. Hand Decimal



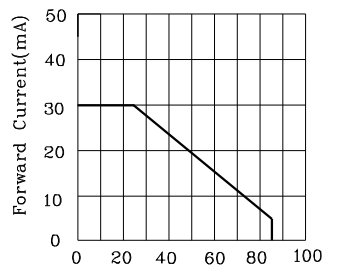
❖ UR



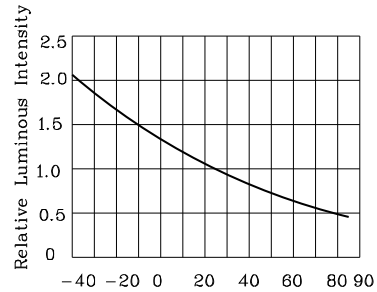
Forward Voltage(V)
FORWARD CURRENT Vs
FORWARD VOLTAGE



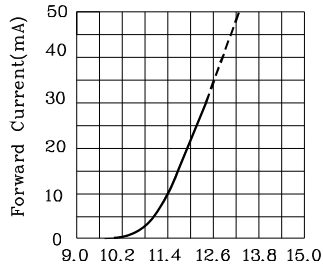
I_F -Forward Current (mA)
LUMINOUS INTENSITY Vs.
FORWARD CURRENT



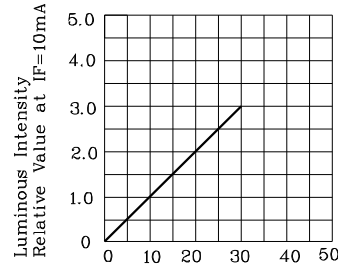
Ambient Temperature T_A ($^\circ\text{C}$)
FORWARD CURRENT
DERATING CURVE



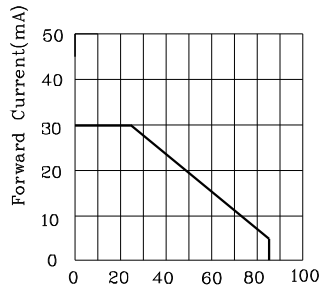
Ambient Temperature T_A ($^\circ\text{C}$)
LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE



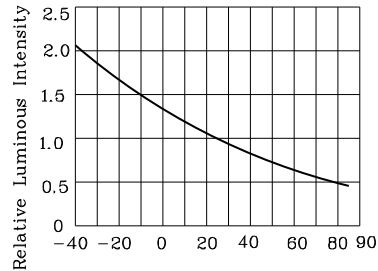
Forward Voltage(V)
FORWARD CURRENT Vs
FORWARD VOLTAGE



IF-Forward Current (mA)
LUMINOUS INTENSITY Vs.
FORWARD CURRENT

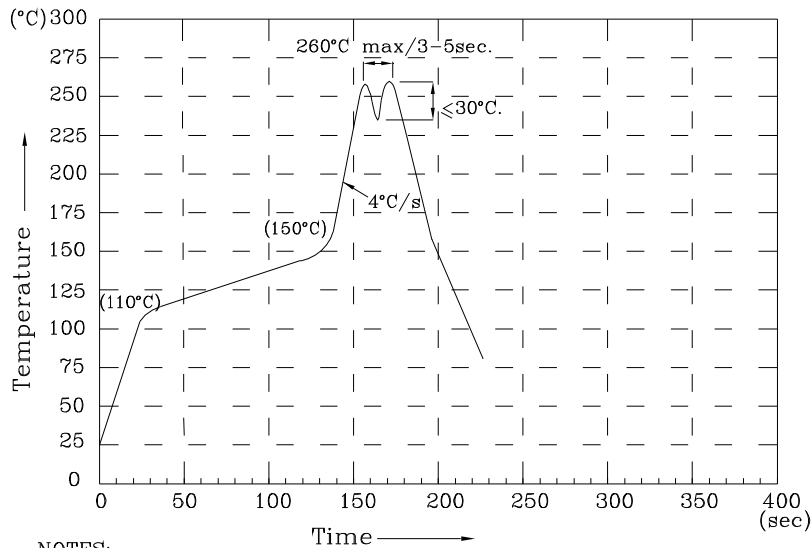


Ambient Temperature Ta (°C)
FORWARD CURRENT
DERATING CURVE



Ambient Temperature Ta (°C)
LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE

Wave Soldering Profile For Lead-free Through-hole LED.



NOTES:

1. Recommend the wave temperature 245°C~260°C. The maximum soldering temperature should be less than 260°C.
2. Do not apply stress on epoxy resins when temperature is over 85 degree°C.
3. The soldering profile apply to the lead free soldering (Sn/Cu/Ag alloy).
4. No more than once.

Remarks:

If special sorting is required (e.g. binning based on forward voltage, Luminous intensity / luminous flux, or wavelength), the typical accuracy of the sorting process is as follows:

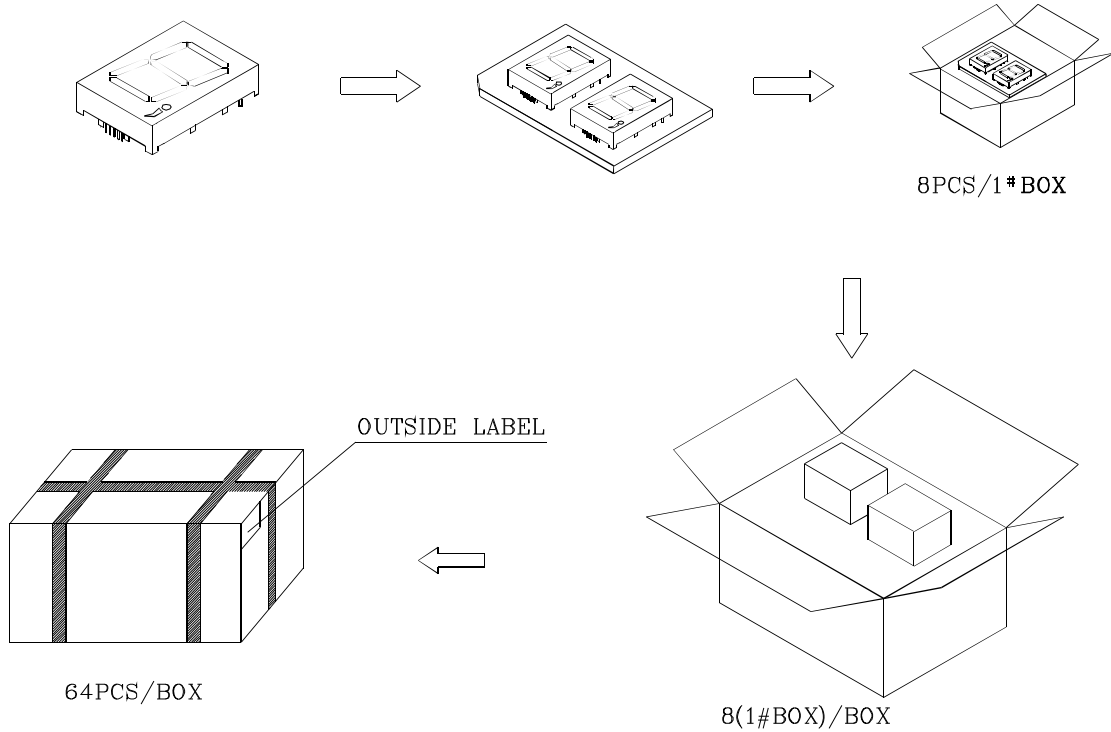
1. Wavelength: +/-1nm
2. Luminous intensity / luminous flux: +/-15%
3. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.

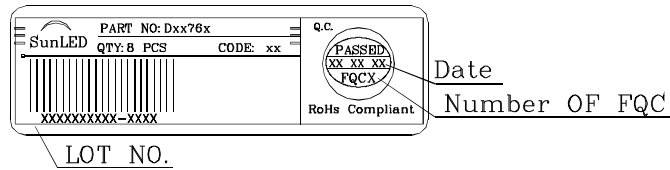


PACKING & LABEL SPECIFICATIONS

DUR76A



Inside LABEL Paste On The 1# Box



Outside LABEL Paste On The Box

